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74VHC161284 IEEE 1284 Transceiver

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General Description

The VHC161284 contains eight bidirectional data buffers and eleven control/status buffers to implement a full IEEE 1284 compliant interface. The device supports the IEEE 1284 standard and is intended to be used in Extended Capabilities Port mode (ECP). The pinout allows for easy connection from the Peripheral (A-side) to the Host (cable side).

Outputs on the cable side can be configured to be either open drain or high drive (\pm 14 mA). The pull-up and pull-down series termination resistance of these outputs on the cable side is optimized to drive an external cable. In addition, all inputs (except HLH) and outputs on the cable side contain internal pull-up resistors connected to the V_{CC} supply to provide proper termination and pull-ups for open drain mode.

Outputs on the Peripheral side are standard LOW-drive CMOS outputs. The DIR input controls data flow on the A_1 - A_8/B_1 - B_8 transceiver pins.

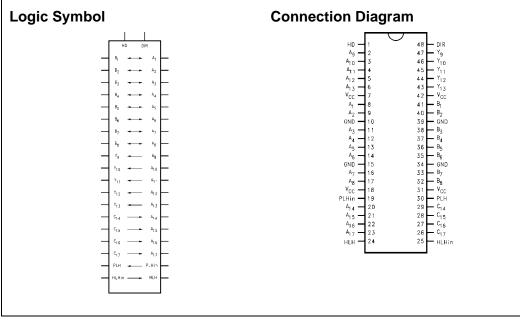
Features

- Supports IEEE 1284 Level 1 and Level 2 signaling standards for bidirectional parallel communications between personal computers and printing peripherals
- Replaces the function of two (2) 74ACT1284 devices
- All inputs have hysteresis to provide noise margin
- B and Y output resistance optimized to drive external cable
- B and Y outputs in high impedance mode during power down
- Inputs and outputs on cable side have internal pull-up resistors
- Flow-through pin configuration allows easy interface between the Peripheral and Host

Ordering Code:

Ordering Number	Package Number	Package Description					
74VHC161284MEA	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide					
74VHC161284MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide					

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.



Pin Descriptions Truth Table Inputs Pin Names Description Outputs HD DIR HIGH Drive Enable Input (Active HIGH) HD DIR **Direction Control Input** B₁–B₈ Data to A₁–A₈, and L L A₁-A₈ Inputs or Outputs $A_9 - A_{13}$ Data to $Y_9 - Y_{13}$ (Note 1) B₁–B₈ Inputs or Outputs C₁₄-C₁₇ Data to A₁₄-A₁₇ A₉-A₁₃ Inputs PLH Open Drain Mode Y₉-Y₁₃ Outputs L Н B₁–B₈ Data to A₁–A₈, and Outputs A₉-A₁₃ Data to Y₉-Y₁₃ A₁₄-A₁₇ C₁₄–C₁₇ Inputs C₁₄-C₁₇ Data to A₁₄-A₁₇ Peripheral Logic HIGH Input PLH_{IN} Н L A₁-A₈ Data to B₁-B₈ (Note 2) Peripheral Logic HIGH Output PLH $A_9 - A_{13}$ Data to $Y_9 - Y_{13}$ (Note 1) HLHIN C₁₄-C₁₇ Data to A₁₄-A₁₇ Host Logic HIGH Input HLH Host Logic HIGH Output PLH Open Drain Mode A₁-A₈ Data to B₁-B₈ Н Н $A_9 - A_{13}$ Data to $Y_9 - Y_{13}$ C₁₄-C₁₇ Data to A₁₄-A₁₇ Note 1: Y₉-Y₁₃ Open Drain Outputs Note 2: B1-B8 Open Drain Outputs Logic Diagram -A8 $A_{9} - A_{13}$ $A_{14} - A_{17}$ PLHin HLH Α1 DI B₁ - B₈ Y₉-Y₁₃ $C_{14} - C_{17}$ PLH HLHin 1-of-5 1-of-4 1-of-8

Absolute Maximum Ratings(Note 3)

Recommended Operating Conditions

	_	Conditions	_	
Supply Voltage		Conditions		
V _{CC}	-0.5V to + 7.0V	Supply Voltage		
Input Voltage (VI) (Note 4)		V _{CC}	4.5V to 5.5V	
A ₁ –A ₁₃ , PLH _{IN} , DIR, HD	–0.5V to V_{CC} + 0.5V	DC Input Voltage (VI)	0V to V _{CC}	
B ₁ –B ₈ , C ₁₄ –C ₁₇ , HLH _{IN}	-0.5V to + 5.5V (DC)	Open Drain Voltage (V _O)	0V to 5.5V	
Β ₁ –Β ₈ , C ₁₄ –C ₁₇ , HLH _{IN}	–2.0V to + 7.0V **40 ns Transient	Operating Temperature (T _A)	-40°C to + 85°C	
Output Voltage (V _O)				
A ₁ –A ₈ , A ₁₄ –A ₁₇ , HLH	-0.5V to V _{CC} + 0.5V			
B ₁ –B ₈ , Y ₉ –Y ₁₃ , PLH	-0.5V to + 5.5V (DC)			
B ₁ –B ₈ , Y ₉ –Y ₁₃ , PLH	-2.0V to + 7.0V*			
	*40 ns Transient			
DC Output Current (I _O)				
A ₁ –A ₈ , HLH	±25 mA			
B ₁ –B ₈ , Y ₉ –Y ₁₃	±50 mA			
PLH (Output LOW)	84 mA			
PLH (Output HIGH)	–50 mA			
Input Diode Current (I _{IK}) (Note 4)				
DIR, HD, A ₉ –A ₁₃ ,				
PLH, HLH, C ₁₄ –C ₁₇	–20 mA			
Output Diode Current (I _{OK})				
A ₁ –A ₈ , A ₁₄ –A ₁₇ , HLH	±50 mA			
B ₁ –B ₈ , Y ₉ –Y ₁₃ , PLH	–50 mA	Note 3: Absolute Maximum continuos rating		
DC Continuous V_{CC} or		which damage to the device may occur. Exposure to these indicated ma adversely affect device reliability. Functional operation under absolute ma		
Ground Current	±200 mA	imum rated conditions is not implied.		
Storage Temperature	–65°C to + 150°C	Note 4: Either voltage limit or current limit is su	ufficient to protect inputs.	
ESD (HBM) Last Passing				
Voltage	2000V			

74VHC161284

0V to $V_{\mbox{\scriptsize CC}}$ 0V to 5.5V -40°C to + 85°C

DC Electrical Characteristics

Symbol	Parameter		v _{cc}	$\textbf{T}_{\textbf{A}}=-40^{\circ}\textbf{C} \text{ to }+85^{\circ}\textbf{C}$	Units	Conditions
			(V)	Guaranteed Limits		
V _{IK}	Input Clamp Diode Voltage		3.0	-1.2	V	I _I = -18 mA
V _{IH}	Minimum HIGH Level Input Voltage	A _n , PLH _{IN} , DIR, HD	4.5 - 5.5	0.7 V _{CC}		
		B _n	4.5 - 5.5	2.0	v	
		C _n	4.5 - 5.5	2.3	v	
		HLH _{IN}	4.5 – 5.5	2.6		
V _{IL}	Maximum LOW Level Input Voltage	A _n , PLH _{IN} , DIR, HD	4.5 - 5.5	0.3 V _{CC}		
		B _n	4.5 - 5.5	0.8	v	
		C _n	4.5 – 5.5	0.8	v	
		HLH _{IN}	4.5 - 5.5	1.6		
ΔVT	Minimum Input Hysteresis	A _n , PLH _{IN} , DIR, HD	4.5 - 5.5	0.4		$V_{T}^{+} - V_{T}^{-}$
		B _n	4.5 – 5.5	0.4	V	$V_{T}^{+} - V_{T}^{-}$
		C _n	5.0	0.8		$V_{T}^{+} - V_{T}^{-}$
		HLH _{IN}	5.0	0.3		$V_{T}^{+} - V_{T}^{-}$
V _{OH}	Minimum HIGH Level Output Voltage	A _n , HLH	4.5	4.4		$I_{OH} = -50 \ \mu A$
			4.5	3.8	v	I _{OH} = -8 mA
		B _n , Y _n	4.5	3.73	v	I _{OH} = -14 mA
		PLH	4.5	4.45		I _{OH} = -500 μA

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DC Electrical Characteristics (Continued)

Symbol	Parameter		Vcc	$T_A = -40^{\circ}C$ to $+85^{\circ}C$	Units	Conditions
Oymbol	Falanciel			Guaranteed Limits	Onita	Conditions
V _{OL}	Maximum LOW Level Output Voltage	A _n , HLH	4.5	0.1		$I_{OL} = 50 \ \mu A$
			4.5	0.44	v	I _{OL} = 8 mA
		B _n , Y _n	4.5	0.77	v	I _{OL} = 14 mA
		PLH	4.5	0.7		$I_{OL} = 84 \text{ mA}$
RD	Maximum Output Impedance	B ₁ -B ₈ , Y ₉ -Y ₁₃	5.0	55	Ω	(Note 5)(Note 6)
	Minimum Output Impedance	B ₁ -B ₈ , Y ₉ -Y ₁₃	5.0	35	Ω	(Note 5)(Note 6)
RP	Maximum Pull-Up Resistance	B ₁ -B ₈ , Y ₉ -Y ₁₃ , C ₁₄ -C ₁₇	5.0	1650	Ω	
	Minimum Pull-Up Resistance	B ₁ -B ₈ , Y ₉ -Y ₁₃ , C ₁₄ -C ₁₇	5.0	1150	Ω	
I _{IH}	Maximum Input Current in HIGH State	A_9 – A_{13} , PLH _{IN} , HD, DIR, HLH _{IN}	5.5	1.0	μA	$V_I = 5.5V$
		C ₁₄ -C ₁₇	5.5	100	μΛ	$V_I = 5.5V$
I _{IL}	Maximum Input Current in LOW State	A ₉ –A ₁₃ , PLH _{IN} , HD, DIR, HLH _{IN}	5.5	-1.0	μA	$V_I = 0.0V$
		C ₁₄ -C ₁₇	5.5	-5.0	mA	$V_{I} = 0.0V$
I _{OZH}	Maximum Output Disable Current	A ₁ —A ₈	5.5	20	μA	$V_O = 5.5V$
	(HIGH)	B ₁ -B ₈	5.5	100	μΛ	$V_O = 5.5V$
I _{OZL}	Maximum Output Disable Current	A ₁ —A ₈	5.5	-20	μA	$V_{O} = 0.0V$
	(LOW)	B ₁ -B ₈	5.5	-5.0	mA	
I _{OFF}	Power Down Output Leakage	B ₁ –B ₈ , Y ₉ –Y ₁₃ , PLH	0.0	100	μA	$V_{O} = 5.5V$
I _{OFF}	Power Down Input Leakage	C ₁₄ -C ₁₇ , HLH _{IN}	0.0	100	μA	$V_I = 5.5V$
I _{OFF} – I _{CC}	Power Down Leakage to V _{CC}		0.0	250	μA	(Note 7)
Icc	Maximum Supply Current		5.5	70	mA	$V_{I} = V_{CC}$ or GNE

Note 5: Output impedance is measured with the output active LOW and active HIGH (HD = HIGH).

Note 6: This parameter is guaranteed but not tested, characterized only.

Note 7: Power-down leakage to V_{CC} is tested by simultaneously forcing all pins on the cable-side (B₁-B₈, Y₉-Y₁₃, PLH, C₁₄-C₁₇ and HLH_{IN} to 5.5V and measuring the resulting I_{CC}.

			C to +85°C		Figure
Symbol	Parameter	V _{CC} = 4.	$V_{CC}=4.5V-5.5V$		
		Min	Max		
t _{PHL}	$A_1 - A_8$ to $B_1 - B_8$	2.0	30.0	ns	Figure 1
PLH	$A_1 - A_8$ to $B_1 - B_8$	2.0	30.0	ns	Figure 2
t _{PHL}	$B_1 - B_8$ to $A_1 - A_8$	2.0	30.0	ns	Figure 3
t _{PLH}	$B_1 - B_8$ to $A_1 - A_8$	2.0	30.0	ns	Figure 3
t _{PHL}	$A_9 - A_{13}$ to $Y_9 - Y_{13}$	2.0	30.0	ns	Figure 1
t _{PLH}	A ₉ -A ₁₃ to Y ₉ -Y ₁₃	2.0	30.0	ns	Figure 2
t _{PHL}	$C_{14}-C_{17}$ to $A_{14}-A_{17}$	2.0	30.0	ns	Figure 3
t _{PLH}	$C_{14}-C_{17}$ to $A_{14}-A_{17}$	2.0	30.0	ns	Figure 3
t _{SKEW}	LH-LH or HL-HL		6.0	ns	(Note 9)
t _{PHL}	PLH _{IN} to PLH	2.0	30.0	ns	Figure 1
t _{PLH}	PLH _{IN} to PLH	2.0	30.0	ns	Figure 2
t _{PHL}	HLH _{IN} to HLH	2.0	30.0	ns	Figure 3
t _{PLH}	HLH _{IN} to HLH	2.0	30.0	ns	Figure 3
PHZ	Output Disable Time	2.0	18.0	ns	Figure 7
PLZ	DIR to A ₁ -A ₈	2.0	18.0	115	r igute /
t _{PZH}	Output Enable Time	2.0	25.0	ns Figu	Figure 8
t _{PZL}	DIR to A ₁ -A ₈	2.0	25.0	115	r igule o
t _{PHZ}	Output Disable Time	2.0	25.0	ns	Figure 9
t _{PLZ}	DIR to B ₁ -B ₈	2.0	25.0	115	r igule 5
t _{pEN}	Output Enable Time	2.0	28.0	ns	Figure 2
	HD to B ₁ -B ₈ , Y ₉ -Y ₁₃	2.0	28.0	115	Figure 2
t _{pDis}	Output Disable Time	2.0	28.0	ns	Figure 2
	HD to B ₁ -B ₈ , Y ₉ -Y ₁₃	2.0	28.0	115	Figure 2
t _{pEn} —t _{pDis}	Output Enable-Output Disable		20.0	ns	
t _{SLEW}	Output Slew Rate				
t _{PLH}	B ₁ -B ₈ , Y ₉ -Y ₁₃	0.05	0.40	1//22	Figure 5
t _{PHL}		0.05	0.40	V/ns	Figure 4
t _r , t _f	t _{RISE} and t _{FALL}		120	20	Figure 6
	B ₁ -B ₈ , Y ₉ -Y ₁₃ (Note 8)		120	ns	(Note 10)

Note 8: Open Drain

Note 9: t_{SKEW} is measured for common edge output transitions and compares the measured propagation delay for a given path type.

(i) $\mathsf{A}_1\text{--}\mathsf{A}_8$ to $\mathsf{B}_1\text{--}\mathsf{B}_8,\,\mathsf{A}_9\text{--}\mathsf{Y}_{13}$ to $\mathsf{Y}_9\text{--}\mathsf{Y}_{13}$

(ii) $B_1 - B_8$ to $A_1 - A_8$

(iii) C_{14} - C_{17} to A_{14} - A_{17}

Note 10: This parameter is guaranteed but not tested, characterized only.

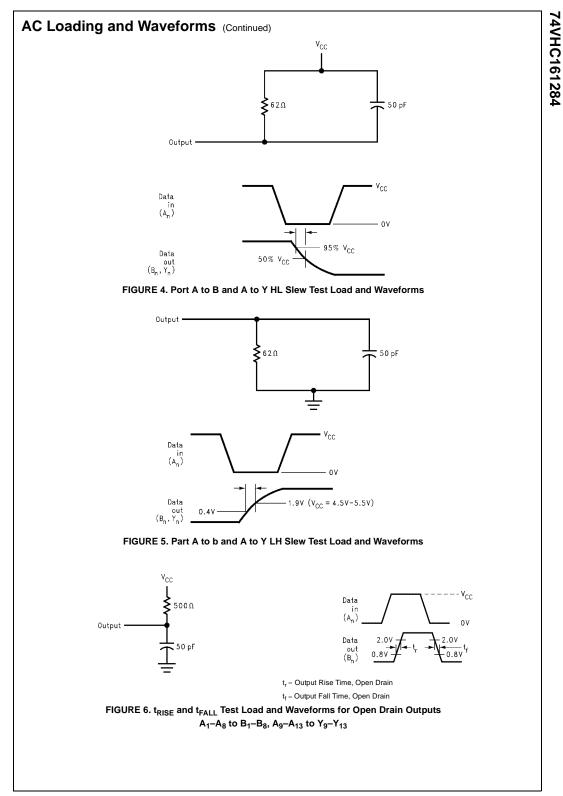
Capacitance (Note 11)

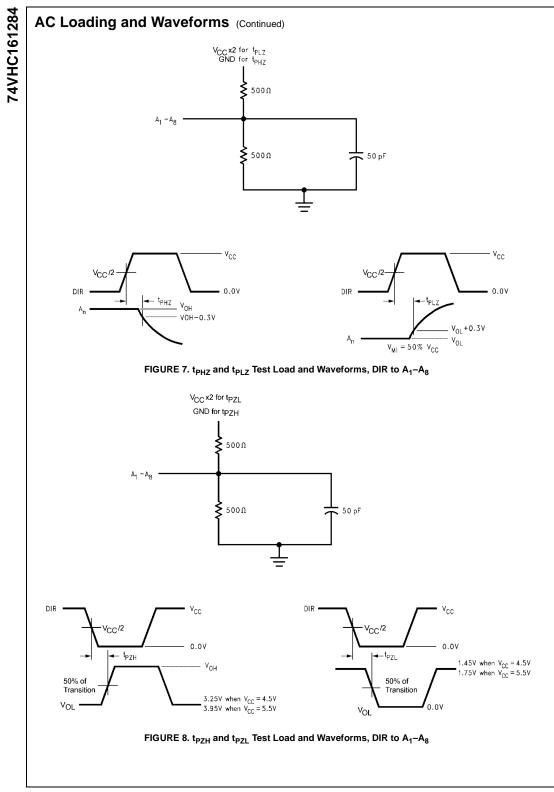
Symbol Parameter		Тур	Units	Conditions
CIN	Input Capacitance	5	pF	$V_{CC} = 0.0V$ (HD, DIR, A_9 — A_{13} , C_{14} — C_{17} , PLH _{IN} and HLH _{IN})
C _{I/O}	I/O Pin Capacitance	12	pF	V _{CC} = 3.3V

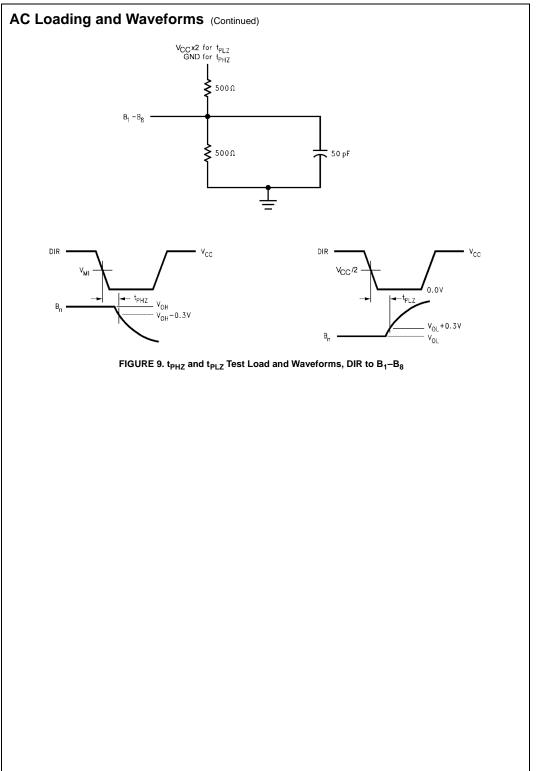
Note 11: Capacitance is measured at frequency = 1 MHz.

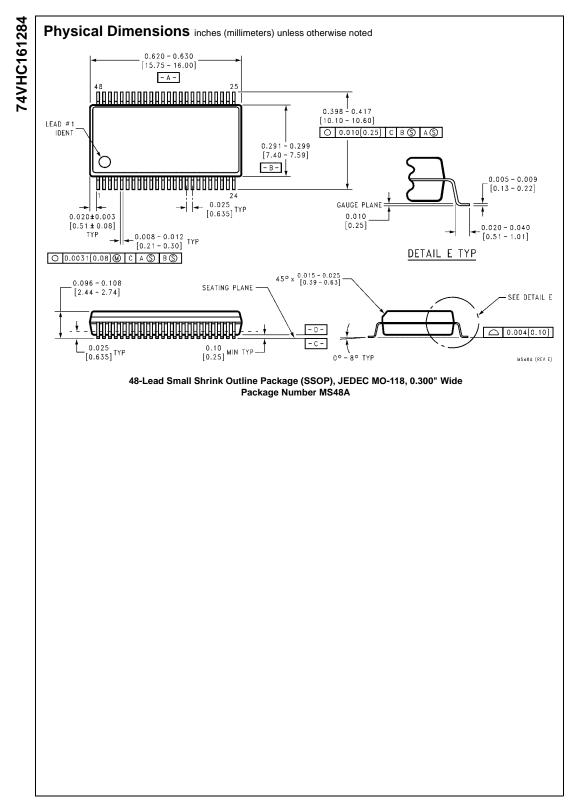


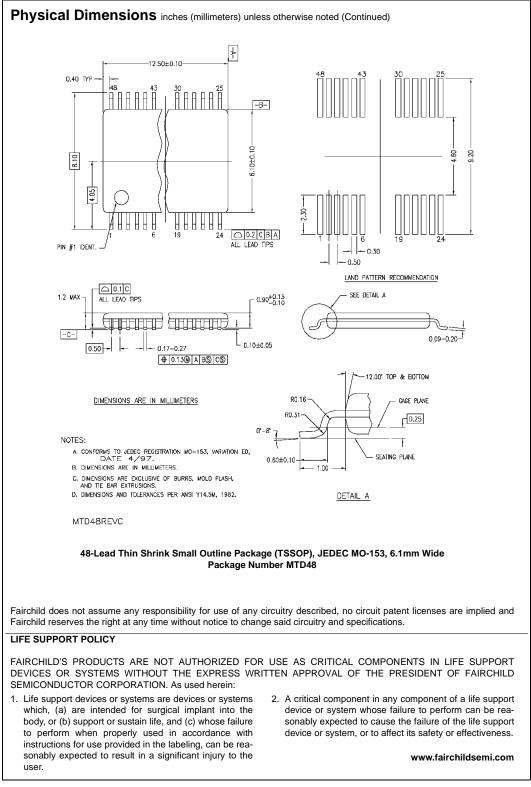
AC Loading and Waveforms Pulse Generator for all pulses: Rate \leq 1.0 MHz; Z_O \leq 50Ω; t_f \leq 2.5 ns, t_r \leq 2.5 ns. V_{CC} Data V_{CC} in ′cc /2 (A_n, PLHin) ٥٧ t_{PHL} → **≶** 500Ω 'nн 50 pF Data out -1.4V Output $(B_n, Y_n, and PLH)$ t_{PHL} VOL $V_{MI} = 50\% V_{CC}$ - V_{CC} Output Data ^tPLH /_{CC}/2 **\$**500Ω in 50 pF 0٧ ^tPLH -v_{он} Data out ΟL FIGURE 1. Part A to B and A to Y Propagation Delay Load and Waveforms --v_{cc} Data $\rm V_{\rm CC}$ Data CC/2 in ′cc ^{/2} (HD) in 0٧ (HD) 0V ^tpenable ^tpdisable Data out (B_n,Y_n) /cc /2 Data out (B_n,Y_n) V_{ОН} - 0.3V V_{ОН} FIGURE 2. Port A to B and a to Y Output Waveforms - V_{CC} Output Data in 500Ω ٥v 50 pF t_{PHL} −V_{OUT} t_{PLH} Data out ′cc /2 V_{CC} /2 FIGURE 3. Port B to A, C to A and HLHin to HLH Propagation Delay Waveforms











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